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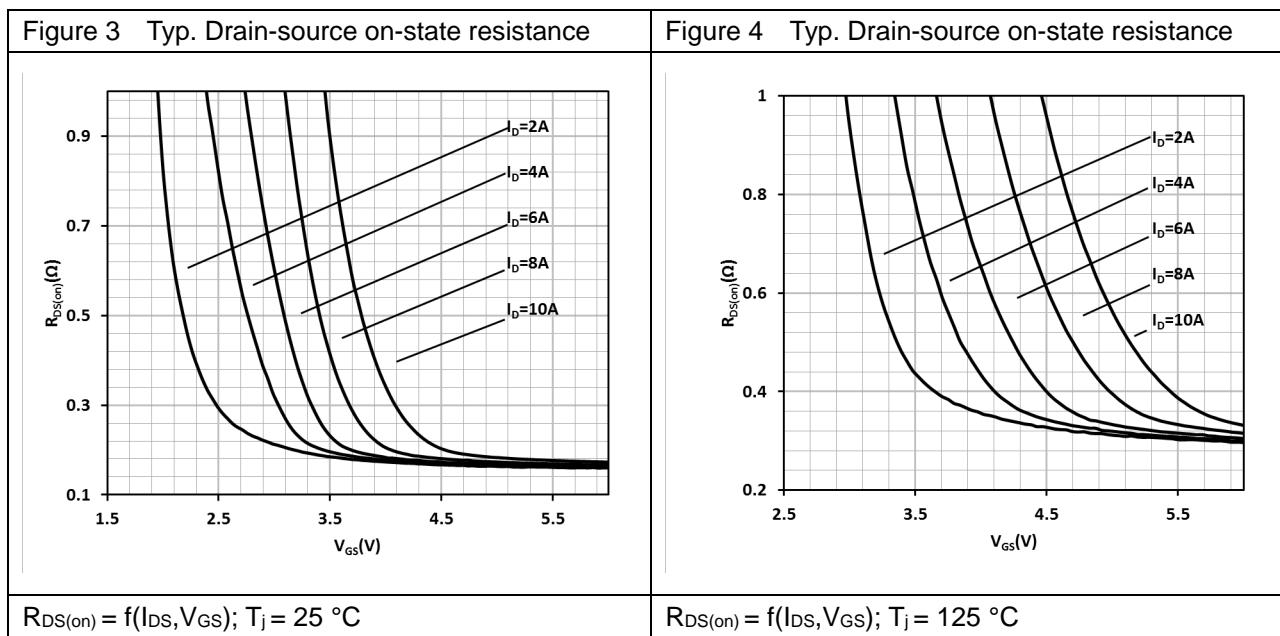
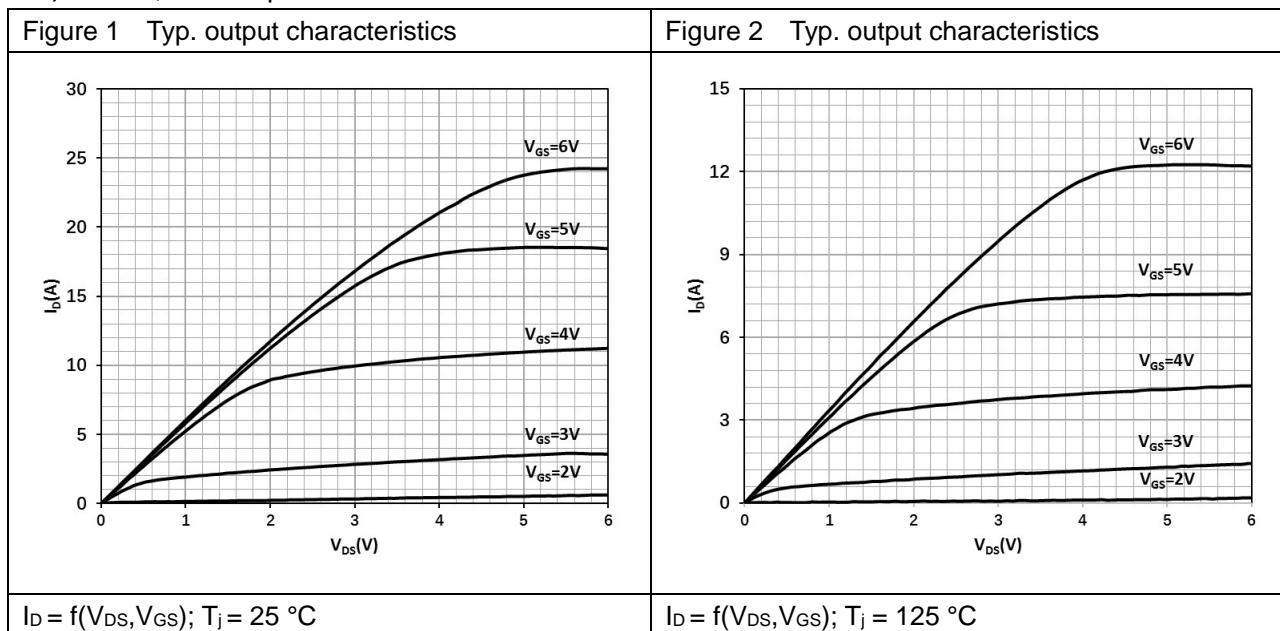






## 8. Electric characteristics diagrams<sup>1</sup>

at  $T_j = 25^\circ\text{C}$ , unless specified otherwise



1. The typical electrical characteristic curves were measured with the parts assembled in DFN 5X6 package.



Figure 9 Typ. transfer characteristics

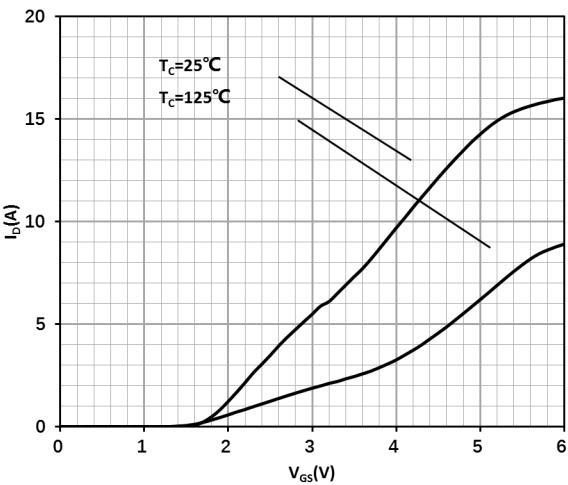
 $I_D = f(V_{GS})$ ;  $V_{DS} = 3$  V

Figure 10 Typ. Gate-to-Source leakage

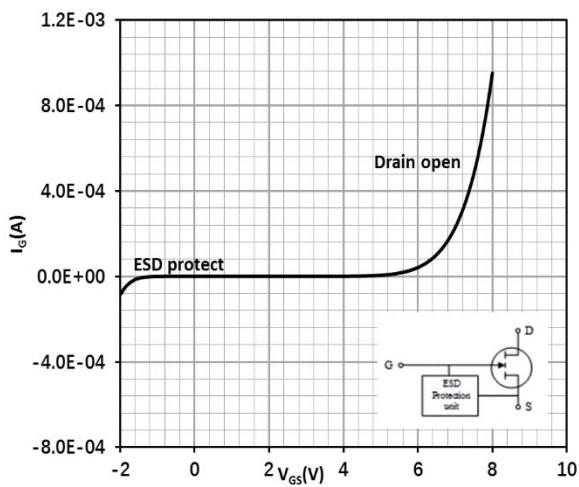
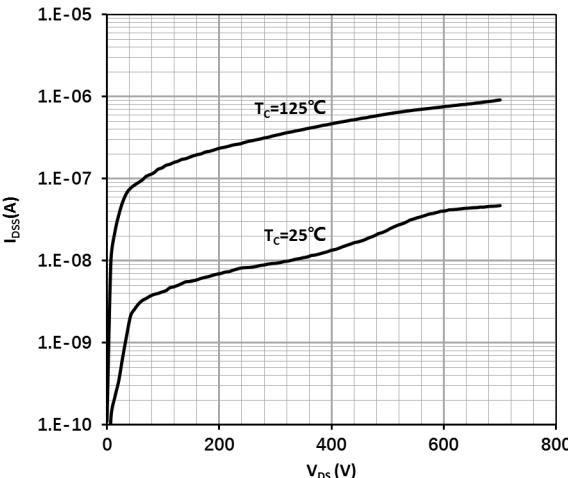
 $I_G = f(V_{GS})$ ;  $I_G$  reverse turn on by ESD unit

Figure 11 Drain-source leakage characteristics

 $I_{DSS} = f(V_{DS})$ ;  $V_{GS} = 0$  V









## 10. Revision history

### Major changes since the last revision

Revision	Date	Description of changes
1.0	2021-10-26	1.0 version release
1.2	2022-04-09	1. Optimize parameter descriptions. 2. Delete $E_{on}/E_{off}/E_{oss}$ from Electric characteristics.

## Important Notice

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